## PACKAGE DIMENSIONS INCH [mm]



ACTIVE AREA $=2.98 \mathrm{~mm}^{2}$

## FEATURES

- High speed
- U.V. enhanced
- Low capacitance
- U.V. window


## DESCRIPTION

The PDU-C104 is a silicon, PIN planar diffused, U.V. enhanced photodiode. Ideal for high speed photoconductive applications. Packaged in a hermetic TO-46 metal can with a U.V. transmitting window.

## APPLICATIONS

- Spectrometers
- Fluorescent analysers
- U.V. meters
- Colorimeters

ABSOLUTE MAXIMUM RATING ( $\mathrm{TA}=25^{\circ} \mathrm{C}$ unless otherwise noted)

| SYMBOL | PARAMETER | MIN | MAX | UNITS |
| :---: | :--- | :---: | :---: | :---: |
| $\mathrm{V}_{\text {BR }}$ | Reverse Voltage |  | 30 | V |
| $\mathrm{~T}_{\text {STG }}$ | Storage Temperature | -55 | +150 | ${ }^{\circ} \mathrm{C}$ |
| $\mathrm{T}_{\mathrm{O}}$ | Operating Temperature Range | -40 | +125 | ${ }^{\circ} \mathrm{C}$ |
| $\mathrm{T}_{\mathrm{S}}$ | Soldering Temperature* $^{*}$ |  | +240 | ${ }^{\circ} \mathrm{C}$ |
| $\mathrm{I}_{\mathrm{L}}$ | Light Current |  | 500 | mA |

*1/16 inch from case for 3 secs max

SPECTRALRESPONSE


WAVELENGTH(nm)

ELECTRO-OPTICAL CHARACTERISTICS (TA=25 ${ }^{\circ} \mathrm{C}$ unless otherwise noted)

| SYMBOL | CHARACTERISTIC | TEST CONDITIONS | MIN | TYP | MAX | UNITS |
| :---: | :--- | :--- | :---: | :---: | :---: | :---: |
| $\mathrm{sc}_{\mathrm{C}}$ | Short Circuit Current | $\mathrm{H}=100 \mathrm{fc}, 2850 \mathrm{~K}$ | 40 | 45 |  | $\mu \mathrm{~A}$ |
| $\mathrm{I}_{\mathrm{D}}$ | Dark Current | $\mathrm{H}=0, \mathrm{~V}_{\mathrm{R}}=5 \mathrm{~V}$ |  | .15 | 1.0 | nA |
| $\mathrm{R}_{\mathrm{SH}}$ | Shunt Resistance | $\mathrm{H}=0, \mathrm{~V}_{\mathrm{R}}=10 \mathrm{mV}$ | .25 | 1.0 |  | $\mathrm{G} \Omega$ |
| $\mathrm{TCR}_{\mathrm{SH}}$ | RSH Temp. Coefficient | $\mathrm{H}=0, \mathrm{~V}_{\mathrm{R}}=10 \mathrm{mV}$ |  | -8 |  | $\% /{ }^{\circ} \mathrm{C}$ |
| $\mathrm{C}_{J}$ | Junction Capacitance | $\mathrm{H}=0, \mathrm{~V}_{\mathrm{R}}=5 \mathrm{~V}^{* *}$ |  | 25 |  | pF |
| $\lambda$ range | Spectral Application Range | Spot Scan | 190 |  | 1100 | nm |
| R | Responsivity | $\mathrm{V}_{\mathrm{R}}=0 \mathrm{~V}, \lambda=254 \mathrm{~nm}$ | .12 | .18 |  | $\mathrm{~A} / \mathrm{W}$ |
| $\mathrm{V}_{\mathbb{R}}$ | Breakdown Voltage | $\mathrm{I}=10 \mu \mathrm{~A}$ | 15 | 25 |  | V |
| NEP | Noise Equivalent Power | $\mathrm{V}_{\mathrm{R}}=10 \mathrm{mV} @$ Peak |  | $1.0 \times 10^{-14}$ |  | $\mathrm{~W} / \sqrt{\mathrm{Hz}}$ |
| tr | Response Time | $\mathrm{RL}=1 \mathrm{~K} \Omega \mathrm{~V}_{\mathrm{R}}=5 \mathrm{~V}$ |  | 48 |  | nS |

Information inthistechnical datasheet is believed to becorrectand reliable. However, no responsibility is assumed for possible inaccuracies or omission. Specifications are subject to change withoutnotice. ${ }^{* *} \mathrm{f}=1 \mathrm{MHz}$

